

# S1F75510

## Charge-pump DC/DC Converter & Voltage Regulator

### ■ DESCRIPTION

The S1F75510 is a power IC designed for use with medium or small capacity TFT-LCD panel modules.

A single chip of this IC is capable of generating three different levels of positive and negative output voltages simultaneously, which are necessary to drive the LCD, by use of a single input power of +2.7 through +3.6V.

Since the S1F75510 does not require external transistors nor diodes as its voltage conversion circuit, its built-in CMOS transistors constituting a complete charge pump type DC/DC converter, it is most suitable for the purpose of reducing the current consumption levels of the LCD modules.

Moreover, the charge pump type DC/DC converter of the S1F75510 can be operated upon the frequencies, which are to be switched over by the mode changing signals, using either of the built-in clock signals or external clock signals optimal to respective cases.

This function can drastically suppress the current consumption of this IC while under light load state, thus exhibiting very high power conversion efficiencies.

### ■ FEATURES

- Supply voltage ..... 2.7V to 3.6V single power input
- Self consumption current (normal mode/blank mode) ..... 200 $\mu$ A / 17 $\mu$ A (TBD)
  - Normal mode: Boosting by use of the internal clock
  - Blank mode: Selectable between boosting by use of the internal clock or by use of the external clock.
- Conversion efficiency of the charge pump part simple substance ..... 95% or more respectively
- Whole conversion efficiency
  - 2.7V at the time of an input 91%
  - 3.0V at the time of an input 82%
- Built-in voltage conversion circuits constituted by charge pump type DC/DC converter,
  - x2 boosting circuit in the positive direction
  - x3 boosting circuit in the positive direction
  - x3 boosting circuit in the negative direction
- Built-in voltage stabilizing circuit
- Capable of outputting the positive supply voltage  $V_{OUT2}$  for the source driver
  - x2 boosting circuit in the positive direction + voltage stabilizing circuit
  - Output voltage: +5.0V
  - Output current: 14mA \*Refer to "Mode changeover circuit "
- Capable of outputting the positive supply voltage  $V_{OUT3}$  for the gate driver
  - x3 boosting circuit in the positive direction
  - Output voltage: +15V
  - Output impedance:  $R_{V_{OUT3}} = 0.7k\Omega$
  - $V_{OUT3} = (V_{OUT2} \times 3) - (R_{V_{OUT3}} \times I_{OUT3})$
- Capable of outputting the negative supply voltage  $V_{OUT4}$  for the gate driver
  - x3 boosting circuit in the negative direction
  - Output voltage: -10V
  - Output impedance:  $R_{V_{OUT4}} = 1k\Omega$
  - $V_{OUT4} = (V_{OUT2} \times -2) - (R_{V_{OUT4}} \times I_{OUT4})$

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- Built-in electric charge discharging circuit
- Built-in shut down function
- Shipping state ..... SSOP3–24pin
- This IC is not of the radiation resistant design nor of the light resistance design.

## ■ BLOCK DIAGRAM

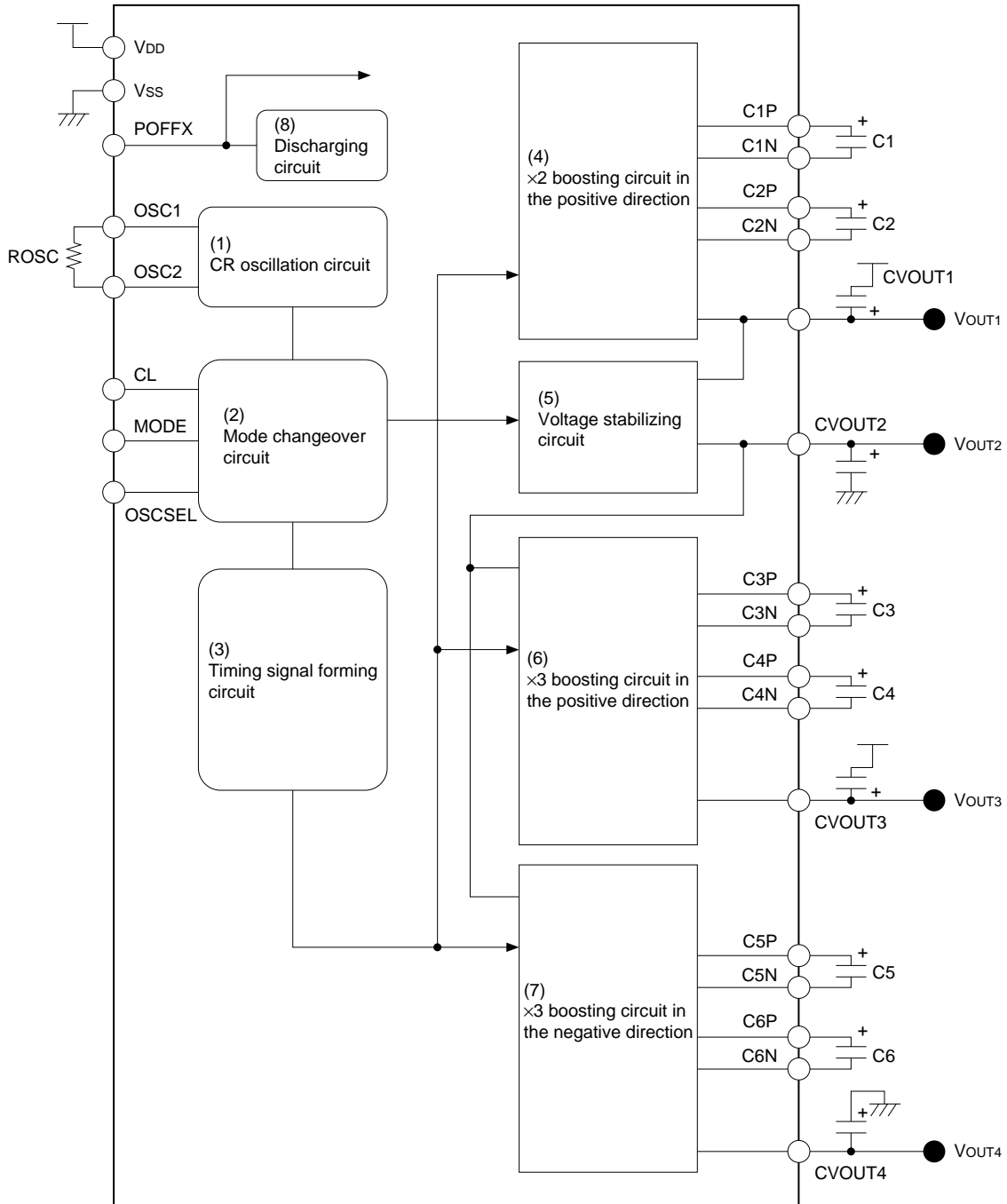


Fig. 1 Block diagram

## ■ DESCRIPTIONS FOR THE BLOCK DIAGRAM

### (1) CR oscillation circuit

The oscillation circuit is constituted by connecting a resistor between the OSC1 pin and the OSC2 pin. The clock signals being generated by this oscillation circuit will become effective as boosting clock signals while the mode changeover signal MODE is on the VDD level (normal mode) or while the mode changeover signal MODE is on the VSS level and, at the same time, when the internal/external clock selection signal OSCSEL is on the VDD level (blank mode · internal clock). When the MODE is set to the VSS level and, at the same time, when the OSCSEL is set to the VSS level (blank mode · external clock), the oscillation will be interrupted.

### (2) Mode changeover circuit

The operation modes of the boosting circuit and voltage stabilizing circuit are being switched over by the mode changeover signal MODE. Also, it selects the clock signals to feed to the timing signal forming circuit from either of the external clock signals or internal clock signals.

### (3) Timing signal forming circuit

This circuit generates the charge pump boosting clock signals. This circuit outputs timing signals of the clock type (internal clock or external clock) having been selected by the mode changeover circuit to drive respective boosting circuits. When the shut down signal POFFX is set to the VSS level, the timing signal stops to interrupt the boosting operation.

### (4) x2 boosting circuit in the positive direction

This circuit makes x2 boosting in the positive direction by charge pump boosting upon the inputted supply voltage  $V_{DD} - V_{SS}$  using the VSS potential as the reference voltage. The x2 boosted output will enter into the voltage stabilizing circuit.

### (5) Voltage stabilizing circuit

This circuit generates the positive supply voltage VOUT2 for the source driver. ON the basis of the built-in reference, this circuit stabilizes the output from the above "(4) x2 boosting circuit in the positive direction" by use of the series regulator.

### (6) x3 boosting circuit in the positive direction

This circuit generates the positive supply voltage VOUT3 for the gate driver. This circuit effects x3 boosting in the positive direction by charge pump boosting upon the voltage  $V_{OUT2} - V_{SS}$  using the VSS potential as the reference voltage.

### (7) x3 boosting circuit in the negative direction

This circuit generates the negative supply voltage VOUT4 for the gate driver. This circuit effects x3 boosting in the negative direction by charge pump boosting upon the voltage  $V_{OUT2} - V_{SS}$  using the VOUT2 potential as the reference voltage.

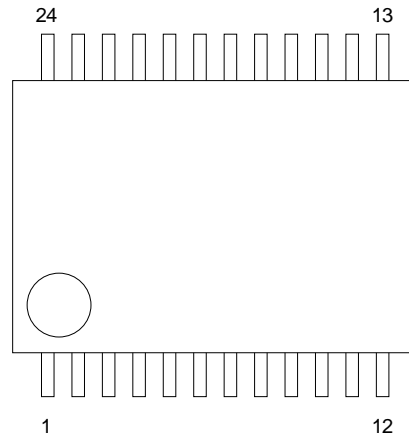
### (8) Electric charge discharging circuit

This circuit discharges the electric charge remaining in the VOUT3 pin and VOUT4 pin to the VSS level. This circuit will work when the POFFX pin is set to the VSS level.

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## ■ PIN ASSIGNMENT

SSOP3–24pin S1F75510M0A0



| Pin No. | Pin name | Pin No. | Pin name |
|---------|----------|---------|----------|
| 1       | C3N      | 13      | MODE     |
| 2       | C3P      | 14      | CL       |
| 3       | C4P      | 15      | POFFX    |
| 4       | C4N      | 16      | OSC1     |
| 5       | VOUT3    | 17      | OSC2     |
| 6       | VDD      | 18      | OSCSEL   |
| 7       | C1N      | 19      | VOUT2    |
| 8       | C1P      | 20      | VOUT4    |
| 9       | VOUT1    | 21      | C6P      |
| 10      | C2P      | 22      | C6N      |
| 11      | C2N      | 23      | C5N      |
| 12      | VSS      | 24      | C5P      |

## ■ PIN DESCRIPTION

(1) CR oscillation circuit · Mode changeover circuit · Timing signal forming circuit · Electric charge discharging circuit

| Pin name  | I/O       | Pin No.   | Function   |      |        |          |           |           |             |          |   |          |           |   |          |   |
|-----------|-----------|---|--|------|--------|----------|-----------|-----------|-------------|----------|---|----------|-----------|---|----------|---|
| POFFX     | I         | 15  | This is the shut down pin. Set it to the VDD level while the IC is in operation. When this signal is set to the VSS level, operations of all the circuits will be interrupted bringing the IC into the shut down state. The electric charge discharging circuit discharges the electric charge remaining in the VOUT3 pin and VOUT4 pin to the VSS level.  |      |        |          |           |           |             |          |   |          |           |   |          |   |
| OSC1      | I         | 16  | This is the CR oscillation circuit gate input pin. This is the pin to connect the oscillation resistor. Fix it to the VSS level in case the built-in oscillation circuit will not be used.   |      |        |          |           |           |             |          |   |          |           |   |          |   |
| OSC2      | O         | 17  | This is the CR oscillation circuit drain input pin. Connect the oscillation resistor between this pin and the OSC1 pin.<br>This should be OFF in use of the built-in oscillation circuit.  |      |        |          |           |           |             |          |   |          |           |   |          |   |
| CL        | I         | 14  | This is the boosting external clock signal input pin. Input the charge pump clock signals under the blank mode into this pin from the external.<br>Fix it to the VSS level in case the external clock will not be used.  |      |        |          |           |           |             |          |   |          |           |   |          |   |
| MODE      | I         | 13  | <p>This is the mode changeover pin.</p> <p>This is the pin for selection between the internal clock and external clock signals.</p> <table border="1"> <thead> <tr> <th>MODE</th> <th>OSCSEL</th> <th>Function</th> </tr> </thead> <tbody> <tr> <td rowspan="2">HIGH(VDD)</td> <td>HIGH(VDD)</td> <td>Normal mode</td> </tr> <tr> <td>LOW(VSS)</td> <td>The boosting clock signals are being generated through the internal oscillation.<br/>The built-in oscillation circuit will operate and the voltage stabilizing circuit will operate.</td> </tr> <tr> <td rowspan="2">LOW(VSS)</td> <td>HIGH(VDD)</td> <td>Blank mode (internal oscillation)<br/>The boosting clock signals are being generated through the internal oscillation.<br/>The built-in oscillation circuit will operate.</td> </tr> <tr> <td>LOW(VSS)</td> <td>Blank mode (external oscillation)<br/>The boosting clock signals are being generated by the external clock.<br/>The built-in oscillation circuit will be interrupted.</td> </tr> </tbody> </table> | MODE | OSCSEL | Function | HIGH(VDD) | HIGH(VDD) | Normal mode | LOW(VSS) | The boosting clock signals are being generated through the internal oscillation.<br>The built-in oscillation circuit will operate and the voltage stabilizing circuit will operate. | LOW(VSS) | HIGH(VDD) | Blank mode (internal oscillation)<br>The boosting clock signals are being generated through the internal oscillation.<br>The built-in oscillation circuit will operate. | LOW(VSS) | Blank mode (external oscillation)<br>The boosting clock signals are being generated by the external clock.<br>The built-in oscillation circuit will be interrupted. |
| MODE      | OSCSEL    | Function  |  |      |        |          |           |           |             |          |   |          |           |   |          |   |
| HIGH(VDD) | HIGH(VDD) | Normal mode   |  |      |        |          |           |           |             |          |   |          |           |   |          |   |
|           | LOW(VSS)  | The boosting clock signals are being generated through the internal oscillation.<br>The built-in oscillation circuit will operate and the voltage stabilizing circuit will operate. |  |      |        |          |           |           |             |          |   |          |           |   |          |   |
| LOW(VSS)  | HIGH(VDD) | Blank mode (internal oscillation)<br>The boosting clock signals are being generated through the internal oscillation.<br>The built-in oscillation circuit will operate.             |  |      |        |          |           |           |             |          |   |          |           |   |          |   |
|           | LOW(VSS)  | Blank mode (external oscillation)<br>The boosting clock signals are being generated by the external clock.<br>The built-in oscillation circuit will be interrupted.                 |  |      |        |          |           |           |             |          |   |          |           |   |          |   |
| OSCSSEL   | I         | 18  |  |      |        |          |           |           |             |          |   |          |           |   |          |   |

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## (2) X2 boosting circuit in the positive direction

| Pin name | I/O | Pin No. | Function   |
|----------|-----|---------|--|
| VOUT1    | O   | 9       | This is the output pin of the x2 boosting circuit in the positive direction.                             |
| C1P      | (O) | 8       | This is the pin to connect the positive side of the VOUT1 output voltage generating flying capacitor C1. |
| C1N      | (O) | 7       | This is the pin to connect the negative side of the VOUT1 output voltage generating flying capacitor C1. |
| C2P      | (O) | 10      | This is the pin to connect the positive side of the VOUT1 output voltage generating flying capacitor C2. |
| C2N      | (O) | 11      | This is the pin to connect the negative side of the VOUT1 output voltage generating flying capacitor C2. |

## (3) Voltage stabilizing circuit

| Pin name | I/O | Pin No. | Function  |
|----------|-----|---------|---|
| VOUT1    | I   | 9       | This is the input power pin (+) for the voltage stabilizing circuit. This pin is being connected to the output pin of the x2 boosting circuit in the positive direction internally, inside this IC. |
| VOUT2    | O   | 19      | This is the output pin of the voltage stabilizing circuit.  |

## (4) X3 boosting circuit in the positive direction

| Pin name | I/O | Pin No. | Function   |
|----------|-----|---------|--|
| VOUT3    | O   | 5       | This is the output pin of the x3 boosting circuit in the positive direction.                             |
| C3P      | (O) | 2       | This is the pin to connect the positive side of the VOUT3 output voltage generating flying capacitor C3. |
| C3N      | (O) | 1       | This is the pin to connect the negative side of the VOUT3 output voltage generating flying capacitor C3. |
| C4P      | (O) | 3       | This is the pin to connect the positive side of the VOUT3 output voltage generating flying capacitor C4. |
| C4N      | (O) | 4       | This is the pin to connect the negative side of the VOUT3 output voltage generating flying capacitor C4. |

(5) X3 boosting circuit in the negative direction

| Pin name | I/O | Pin No. | Function   |
|----------|-----|---------|--|
| VOUT4    | O   | 20      | This is the output pin of the X3 boosting circuit in the negative direction.                             |
| C5P      | (O) | 24      | This is the pin to connect the positive side of the VOUT4 output voltage generating flying capacitor C5. |
| C5N      | (O) | 23      | This is the pin to connect the negative side of the VOUT4 output voltage generating flying capacitor C5. |
| C6P      | (O) | 21      | This is the pin to connect the positive side of the VOUT4 output voltage generating flying capacitor C6. |
| C6N      | (O) | 22      | This is the pin to connect the negative side of the VOUT4 output voltage generating flying capacitor C6. |

(6) Power pins

| Pin name | I/O | Pin No. | Function                         |
|----------|-----|---------|----------------------------------|
| VDD      | I   | 6       | This is the input power pin (+). |
| VSS      | I   | 12      | This is the input power pin (-). |

# S1F75510

## ■ FUNCTIONAL DESCRIPTION

### ● Operational description

The S1F75510 is a power supply IC for TFT-LCD panel modules. With this IC chip alone, 3 positive and 3 negative levels of output voltages required for driving the LCD can be generated simultaneously by a single power input.

The voltage converter circuit for the S1F75510 does not require an external transistor or diode since it is equipped with a charge pump type DC/DC converter configured with a built-in CMOS transistor, enabling low power consumption of the LCD module.

Generating voltage levels are:

- Positive boosting supply voltage necessary for the voltage stabilizing circuit ( $V_{OUT1}$ )
- Positive stabilized supply voltage necessary for the source driver ( $V_{OUT2}$ )
- Positive and negative boosting supply voltages necessary for the gate driver ( $V_{OUT3}$  and  $V_{OUT4}$ )

The  $V_{OUT1}$  supply voltage is being generated by the charge pump type DC/DC converter (x2 boosting circuit in the positive direction). It makes x2 boosting in the positive direction of the potential difference occurring between the  $V_{DD} - V_{SS}$  using the  $V_{SS}$  potential as the reference voltage.

The  $V_{OUT2}$  supply voltages is being generated by the series regulator stabilizing the potential difference occurring between the  $V_{OUT1} - V_{SS}$  using the  $V_{SS}$  potential as the reference voltage.

The  $V_{OUT3}$  supply voltage is being generated by the charge pump type DC/DC converter (x3 boosting circuit in the positive direction). It makes x3 boosting in the positive direction of the potential difference occurring between the  $V_{OUT2} - V_{SS}$  using the  $V_{SS}$  potential as the reference voltage.

The  $V_{OUT4}$  supply voltage is being generated by the charge pump type DC/DC converter (x3 boosting circuit in the negative direction). It makes x3 boosting in the negative direction of the potential difference occurring between the  $V_{OUT2} - V_{SS}$  using the  $V_{OUT2}$  potential as the reference voltage.

Indicated below is the system configuration diagram for the power circuit.

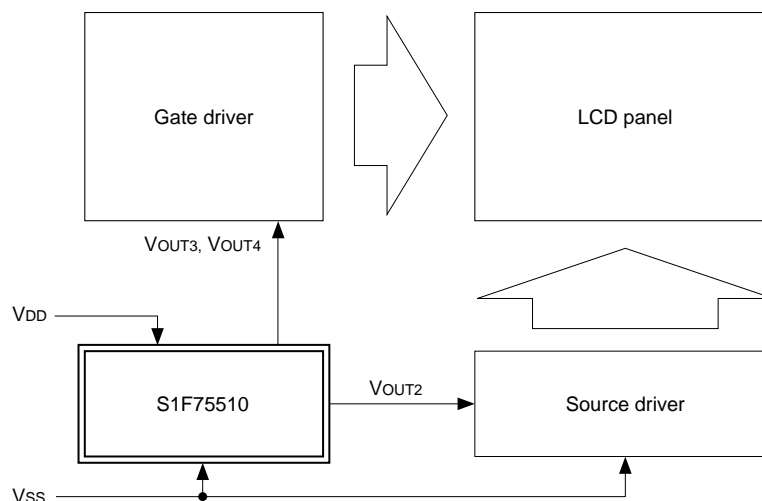


Fig. 2 System configuration diagram



Indicated below is the potential correlation diagram inside the system as is shown in Fig. 2.

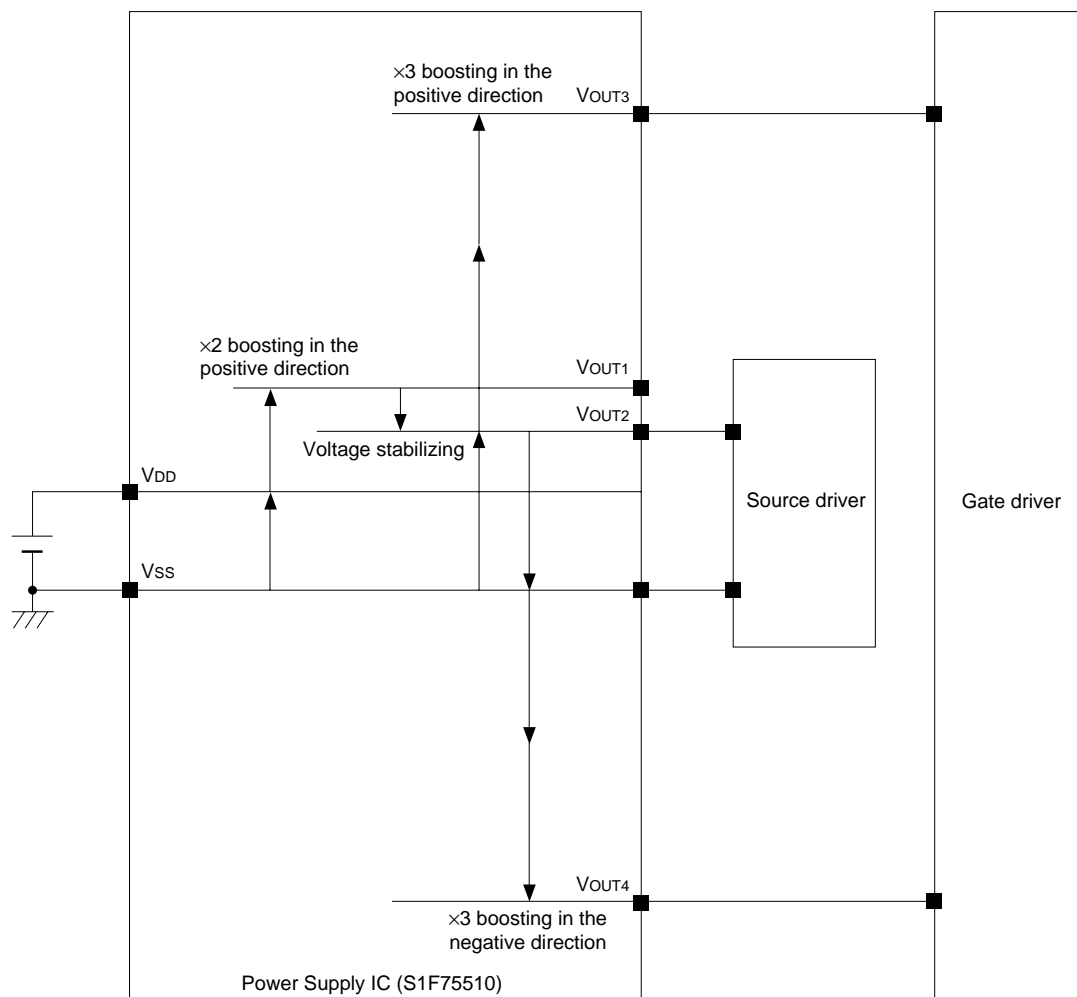


Fig. 3 Potential correlation diagram inside the system

## ● CR oscillation circuit

The S1F75510 incorporates a CR oscillation circuit as the oscillation circuit for the boosting clock signals. This circuit is to be used connecting the external oscillation resistor RO<sub>SC</sub> between the OSC1 pin and the OSC2 pin. The CR oscillation circuit will stop operation under the blank mode and when using the external clock (MODE = V<sub>SS</sub> level and OSCSEL = V<sub>SS</sub> level) or under the shut down state (POFFX = V<sub>SS</sub> level). Also, the oscillation will be interrupted by setting the OSC1 pin to the V<sub>SS</sub> level and, at the same time, setting the OSC2 pin into open state.

In this document, the electrical characteristics are referred to as the external oscillation resistance value, RO<sub>SC</sub>=1MΩ.

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## ● Mode changeover circuit

By external settings of the mode changeover signal MODE and the internal/external clock selection signal OSCSEL, the charge pump boosting can be driven under optimum frequencies. Since the current consumption of the IC can be suppressed drastically under the blank mode, it is possible to achieve high power conversion efficiency even under light load operations.

The closer to 50% the external clock duty in the blank mode gets, the more optimum it becomes.

| MODE pin  | OSCSEL pin            | Mode name   | Max. output current                             | Built-in CR oscillation circuit |
|-----------|-----------------------|---|---|---------------------------------|
| HIGH(VDD) | HIGH(VDD)<br>LOW(VSS) | Normal mode   | VOUT2: 14mA *1<br>VOUT3: 0.7kΩ<br>VOUT4: 1kΩ    | In operation                    |
| LOW(VSS)  | HIGH(VDD)             | Blank mode<br>(internal oscillation)                                  | VOUT2: 300μA *2<br>VOUT3: 4.0kΩ<br>VOUT4: 4.0kΩ | In operation                    |
|           | LOW(VSS)              | Blank mode<br>(external oscillation)<br>duty=50% when<br>CL = 1.25kHz | VOUT2: 300μA *2<br>VOUT3: 4.0kΩ<br>VOUT4: 4.0kΩ | In standstill                   |

\*1 When IOUT3 = 300μA, IOUT3 = 300μA:

IOUT2 (Max.) < 16.0mA – (3 × IOUT3 + 3 × IOUT4) must be satisfied.

\*2 When IOUT3 = 30μA, IOUT3 = 30μA:

IOUT2 (Max.) < 0.50mA – (3 × IOUT3 + 3 × IOUT4) must be satisfied.

## ● Timing signal forming circuit

This circuit generates the clock signals necessary for charge pump boosting using the internal oscillation or using external clock signals.

Two different types of capacitors are being used as the charge pump capacitors, one being the flying capacitor which shifts between the charging state and the discharging state and the other being the smoothing capacitor which preserves the electric charge. The operating frequency of the flying capacitor should equal to the frequency of the charge pump clock being generated by this timing signal forming circuit.

Under the shut down state (POFFX = Vss level), the charge pump clock stops operation and all the boosting operations of this IC will be interrupted. The operating frequencies of the flying capacitor are as follows.

| MODE pin  | OSCSEL pin            | Mode name                    | Operating frequencies of the flying capacitor |                                       |                                       |
|-----------|-----------------------|------------------------------|---|---------------------------------------|---------------------------------------|
|           |                       |                              | ×2 boosting in the positive direction         | ×3 boosting in the positive direction | ×3 boosting in the negative direction |
| HIGH(VDD) | HIGH(VDD)<br>LOW(VSS) | Normal mode                  | 10kHz   | 10kHz                                 | 10kHz                                 |
| LOW(VSS)  | HIGH(VDD)             | Blank mode                   | 625kHz  | 625kHz                                | 625kHz                                |
|           | LOW(VSS)              | Blank mode<br>CL = fosc (Hz) | 1/2 × fosc Hz                                 | 1/2 × fosc Hz                         | 1/2 × fosc Hz                         |

## ● X2 boosting circuit in the positive direction

The x2 boosting circuit in the positive direction generates the voltages necessary to input into the voltage stabilizing circuit. It makes x2 boosting in the positive direction of the potential difference occurring between the  $V_{DD} - V_{SS}$  using the  $V_{SS}$  potential as the reference voltage to output through the  $V_{OUT1}$  pin.

Under the blank mode, since the boosting operation is being carried out with the flying capacitor C2 stopping its operation, the current consumption can be suppressed accordingly.

The theoretical equation (output voltage value under the idealistic non-load state) for the  $V_{OUT1}$  becomes as follows:

$$V_{OUT1} = (V_{DD} - V_{SS}) \times 2$$

Actually, when a load is connected to the  $V_{OUT1}$ , the output voltage will drop to the value represented by the equation indicated below.

$$V_{OUT1} = (V_{DD} - V_{SS}) \times 2 - R_{VOUT1} \times I_{VOUT1}$$

$R_{VOUT1}$  : Output impedance of the x2 boosting circuit in the positive direction

$I_{VOUT1}$  : Load current

## ● Voltage stabilizing circuit

The voltage stabilizing circuit stabilizes the voltage being output through the  $V_{OUT1}$  pin by the series regulator to output the positive supply voltage for the source driver through the  $V_{OUT2}$  pin.

The output voltage setting for the  $V_{OUT2}$  pin should be Typ. +5.0V (TBD).

As for  $I_{OUT2}$ , in order to obtain normal output voltage value through the  $V_{OUT2}$  pin, use the IC within the range of the max. load current (Refer to "Mode changeover circuit").

The circuit configuration · connection diagram for the voltage stabilizing circuit is as follows:

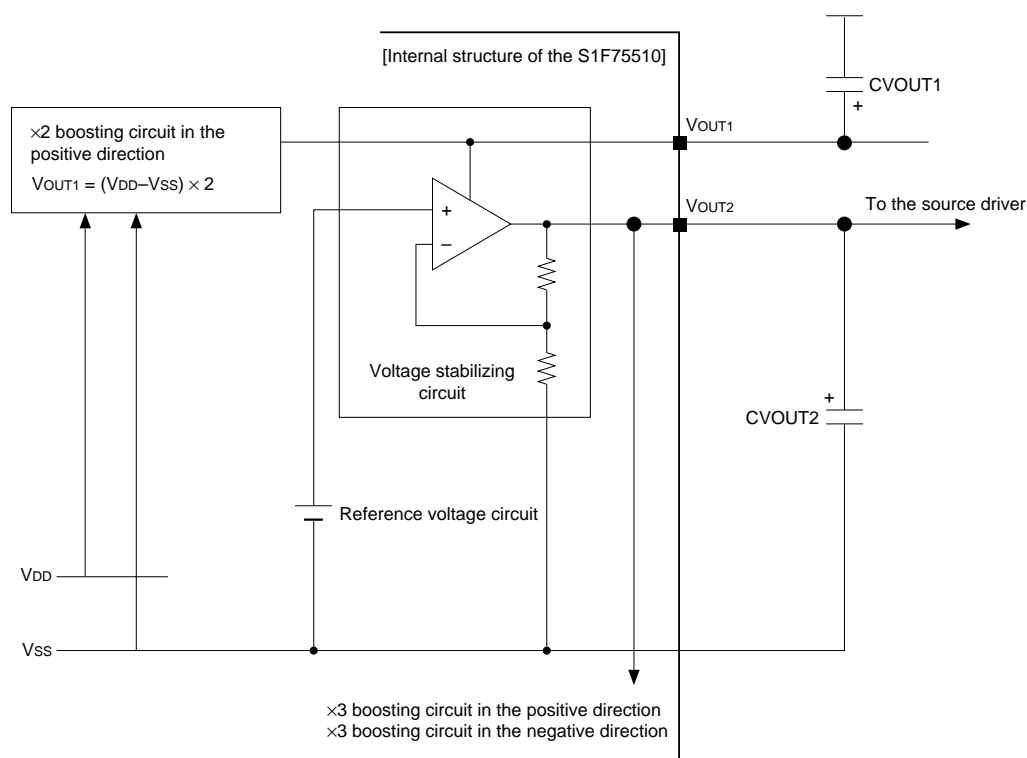


Fig. 4 Configuration diagram of the voltage stabilizing circuit

## ● X3 boosting circuit in the positive direction

The x3 boosting circuit in the positive direction generates the VOUT3 output voltage, means the positive supply voltage for the gate driver. It makes x3 boosting in the positive direction of the potential difference occurring between the VOUT2 – VSS using the VSS potential as the reference voltage, by charge pump boosting, to output through the VOUT3 pin.

The theoretical equation (output voltage value under the idealistic non-load state) for the VOUT3 becomes as follows:

$$V_{OUT3} = (V_{OUT2} - V_{SS}) \times 3$$

Actually, when a load is connected to the VOUT3, the output voltage will drop to the value represented by the equation indicated below.

$$V_{OUT3} = (V_{OUT2} - V_{SS}) \times 3 - (R_{VOUT3} \times I_{VOUT3})$$

R<sub>VOUT3</sub> : Output impedance of the x3 boosting circuit in the positive direction

I<sub>VOUT3</sub> : Load current

It means that the VOUT3 voltage will drop by the load.

To acquire desired output voltage, use the IC within the range of the specified load (Refer to “Mode changeover circuit”).

## ● X3 boosting circuit in the negative direction

The x3 boosting circuit in the negative direction generates the VOUT3 output voltage, means the negative supply voltage for the gate driver. It makes x3 boosting in the negative direction of the potential difference occurring between the VOUT2 – VSS using the VOUT2 potential as the reference voltage, by charge pump boosting, to output through the VOUT4 pin.

The theoretical equation (output voltage value under the idealistic non-load state) for the VOUT4 becomes as follows:

$$V_{OUT4} = (V_{OUT2} - V_{SS}) \times (-2) \quad (\text{The voltage value using the } V_{SS} \text{ potential as the reference voltage})$$

Actually, when a load is connected to the VOUT4, the output voltage will drop to the value represented by the equation indicated below.

$$V_{OUT4} = (V_{OUT2} - V_{SS}) \times (-2) - (R_{VOUT4} \times I_{VOUT4})$$

R<sub>VOUT4</sub> : Output impedance of the x3 boosting circuit in the negative direction

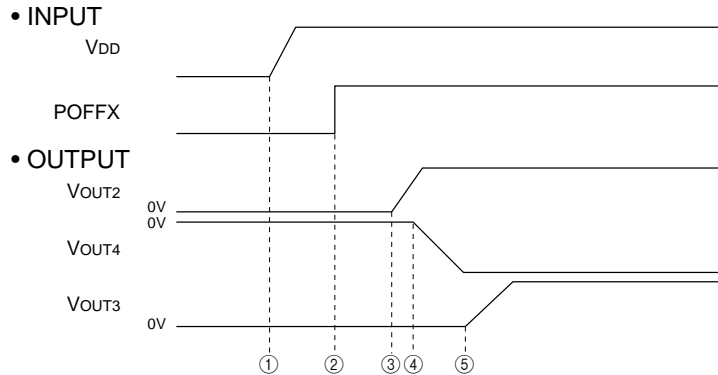
I<sub>VOUT4</sub> : Load current

It means that the VOUT4 voltage will drop by the load.

To acquire desired output voltage, use the IC within the range of the specified load (Refer to “Mode changeover circuit”).

## ● Start-up sequence

The ON sequence when the S1F75510 starts up is described as follows.



- ① The S1F75510 is energized.
- ② The operation start signal is input and the internal booster (VOUT1) starts up.
- ③ The positive power supply for source driver (stabilized output) VOUT2 starts up.
- ④ The negative power supply for gate driver VOUT4 starts up.
- ⑤ The positive power supply for gate driver VOUT3 starts up.

## ● Discharge circuit

The S1F75510 is equipped with a built-in circuit that discharges the positive power supply for source driver (stabilized output) VOUT2, positive power supply for gate driver VOUT3 and negative power supply for gate driver VOUT4 to the VSS level. This discharge circuit starts discharging VOUT2, VOUT3 and VOUT4 when the POFFX terminal is turned to the VSS level.

# S1F75510

## ■ ABSOLUTE MAXIMUM RATINGS

| Item                           | Symbol | Rating |           | Unit | Applicable pin | Remarks   |
|--------------------------------|--------|--------|-----------|------|----------------|-----------|
|                                |        | Min.   | Max.      |      |                |           |
| Input supply voltage           | VDD    | - 0.3  | 4.0       | V    | VDD            | —         |
| Output voltage 1               | VOUT1  | - 0.3  | 7.5       | V    | VOUT1          | —         |
| Output voltage 2               | VOUT2  | - 0.3  | 7.5       | V    | VOUT2          | —         |
| Output voltage 3               | VOUT3  | - 0.3  | 22.5      | V    | VOUT3          | —         |
| Output voltage 4               | VOUT4  | - 15.0 | 0.3       | V    | VOUT4          | —         |
| Input pin voltage 1            | VIN    | - 0.3  | VDD + 0.3 | V    | <Note 1>       | —         |
| Input current                  | IVDD   | —      | 50        | mA   | VDD            |           |
| Output current 1               | IVOUT1 | —      | 20        | mA   | VOUT1          | —         |
| Output current 2               | IVOUT2 | —      | 20        | mA   | VOUT2          | —         |
| Output current 3               | IVOUT3 | —      | 5         | mA   | VOUT3          | —         |
| Output current 4               | IVOUT4 | —      | 5         | mA   | VOUT4          | —         |
| Allowable dissipation          | Pd1    | —      | 520       | mW   | —              | Ta ≤ 25°C |
| Operating temperature          | Topr   | - 30   | 85        | °C   | —              | —         |
| Storage temperature            | Tstg   | - 55   | 150       | °C   | —              | —         |
| Soldering temperature and time | Tsol   | —      | 260·10    | °C·s | —              | At leads  |

<Note 1> The applicable pins are POFFX, OSC1, CL, MODE and OSCSEL.

<Note 2> Do not apply external voltage to the output pins and the pin connecting to the capacitor.

<Note 3> Use of the IC under any conditions exceeding the above absolute maximum ratings may cause malfunctioning or permanent breakdown. Or, even if the IC may operate normally temporarily, the reliability may greatly drop.

## ■ ELECTRICAL CHARACTERISTICS

### ● DC characteristics

In case particular designations are not made (Note 1): Ta = 25°C

| Item  | Symbol | Conditions  | Rating |      |        | Unit | Remarks |
|---|--------|---|--------|------|--------|------|---------|
|   |        |   | Min.   | Typ. | Max.   |      |         |
| Input supply voltage  | VDD    | Applicable pin: VDD   | 2.7    | 3.0  | 3.6    | V    | —       |
| High level input voltage  | VIH    | —   | 0.8VDD | —    | VDD    | V    | 2       |
| Low level input voltage   | VIL    | —   | 0      | —    | 0.2VDD | V    | 2       |
| Input leak current 1  | ILIN1  | VSS ≤ VI ≤ VDD,<br>VDD = 2.7 to 3.6V  | - 0.5  | —    | 0.5    | μA   | 2       |
| Current consumption 1   | IOP1   | VDD = 3.0V, no load<br>Under the normal mode                                | —      | 200  | 280    | μA   | —       |
| Current consumption 2   | IOP2   | VDD = 3.0V, no load<br>Under the blank mode<br>CL = 1.25kHz, duty = 50%     | —      | 17   | 30     | μA   | —       |
| Power conversion efficiency 1<br>(Overall efficiency including<br>the stabilized outputs) | Peff1  | Under the normal mode<br>VDD = 2.7V<br>VDD = 3.0V                           | —      | 91   | —      | %    | 3       |
|   |        |   | —      | 82   | —      |      |         |
| Power conversion efficiency 2<br>(Overall efficiency including<br>the stabilized outputs) | Peff2  | Blank mode exterior<br>CL = 1.25kHz, duty = 50%<br>VDD = 2.7V<br>VDD = 3.0V | —      | 89   | —      | %    | 4       |
|   |        |   | —      | 80   | —      |      |         |
| Resting current   | IQ     | VDD = 3.6V<br>POFFX = LOW   | —      | —    | 1.0    | μA   | —       |

<Note 1> Conditions on the operation mode, external parts constant, pins, etc. in case particular designations are not made are as follows.

Connection and parts constant : Standard connection 1, 10.1

MODE pin : MODE = HIGH (Normal mode)

CL pin : CL = LOW (Fixed voltage)

<Note 2> The applicable pins are POFFX, OSC1, CL, MODE, OSCSEL

<Note 3> Load conditions: IVOUT2 = 10mA, IVOUT3 = 100μA, IVOUT4 = 100μA

Conversion efficiency =  $[(V_{OUT2} \times I_{VOUT2}) + (V_{OUT3} \times I_{VOUT3}) + (V_{OUT4} \times I_{VOUT4})] / (V_{DD*} \times I_{VDD*}) \times 100$

<Note 4> Load conditions: IVOUT2 = 200μA, IVOUT3 = 10μA, IVOUT4 = 10μA

Conversion efficiency =  $[(V_{OUT2} \times I_{VOUT2}) + (V_{OUT3} \times I_{VOUT3}) + (V_{OUT4} \times I_{VOUT4})] / (V_{DD*} \times I_{VDD*}) \times 100$

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## ● Characteristics of X2 boosting in the positive direction + stabilized output

In case particular designations are not made: Ta = 25°C

| Item   | Symbol   | Conditions            | Rating |      |      | Unit | Remarks |
|--|----------|-----------------------|--------|------|------|------|---------|
|  |          |                       | Min.   | Typ. | Max. |      |         |
| VOUT1 output impedance (Normal mode)         | RVOUT1-1 | Applicable pin: VOUT1 | —      | 20   | 25   | Ω    | 5       |
| VOUT1 output impedance (Blank mode)          | RVOUT1-2 | Applicable pin: VOUT1 | —      | 400  | 600  | Ω    | 6       |
| VOUT2 Stabilized output voltage              | VOUT2    | Applicable pin: VOUT2 | 4.90   | 5.00 | 5.10 | V    | 7       |
| VOUT2 Stabilized output saturated resistance | RVOUT2   | Applicable pin: VOUT2 | —      | 5    | 10   | Ω    | 8       |

<Note 5> VDD = 2.7V to 3.6V, Load condition: IVOUT1 = 10mA

<Note 6> VDD = 2.7V to 3.6V, Load condition: IVOUT1 = 200mA

<Note 7> VDD = 2.7V to 3.6V, Load condition: IVOUT2 = 1mA

Ta = -10 to +70°C

<Note 8> VDD = 2.7V to 3.6V, Load condition: IVOUT2 = 10mA

## ● Characteristics of X3 boosting in the positive direction and X3 boosting in the negative direction

In case particular designations are not made: Ta = 25°C

| Item                                 | Symbol   | Conditions            | Rating |      |      | Unit | Remarks |
|--------------------------------------|----------|-----------------------|--------|------|------|------|---------|
|                                      |          |                       | Min.   | Typ. | Max. |      |         |
| VOUT3 output impedance (Normal mode) | RVOUT3-1 | Applicable pin: VOUT3 | —      | 0.7  | 1.0  | Ω    | 9       |
| VOUT3 output impedance (Blank mode)  | RVOUT3-2 | Applicable pin: VOUT3 | —      | 4.0  | 5.0  | Ω    | 10      |
| VOUT4 output impedance (Normal mode) | RVOUT4-1 | Applicable pin: VOUT4 | —      | 1.0  | 1.3  | Ω    | 11      |
| VOUT4 output impedance (Blank mode)  | RVOUT4-2 | Applicable pin: VOUT4 | —      | 4.0  | 5.0  | Ω    | 12      |

<Note 9> VDD = 2.7V to 3.6V, Load condition: IVOUT3 = 100μA

<Note 10> VDD = 2.7V to 3.6V, Load condition: IVOUT3 = 10μA

<Note 11> VDD = 2.7V to 3.6V, Load condition: IVOUT4 = 100μA

<Note 12> VDD = 2.7V to 3.6V, Load condition: IVOUT4 = 10μA

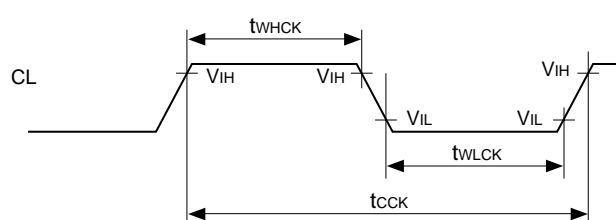


## ● AC characteristics

Measurement conditions for the AC characteristics

- Input signal level  $V_{IH} = 0.8V_{DD}$  (V)  
 $V_{IL} = 0.2V_{DD}$  (V)
- Input signal rise time  $T_r = \text{Max. } 100\text{ns}$
- Input signal fall time  $T_f = \text{Max. } 100\text{ns}$
- $V_{DD} = 2.7 \text{ to } 3.6\text{V}$ ,  $V_{SS} = 0\text{V}$
- $T_a = -30 \text{ to } +85^\circ\text{C}$

CL inputting timing

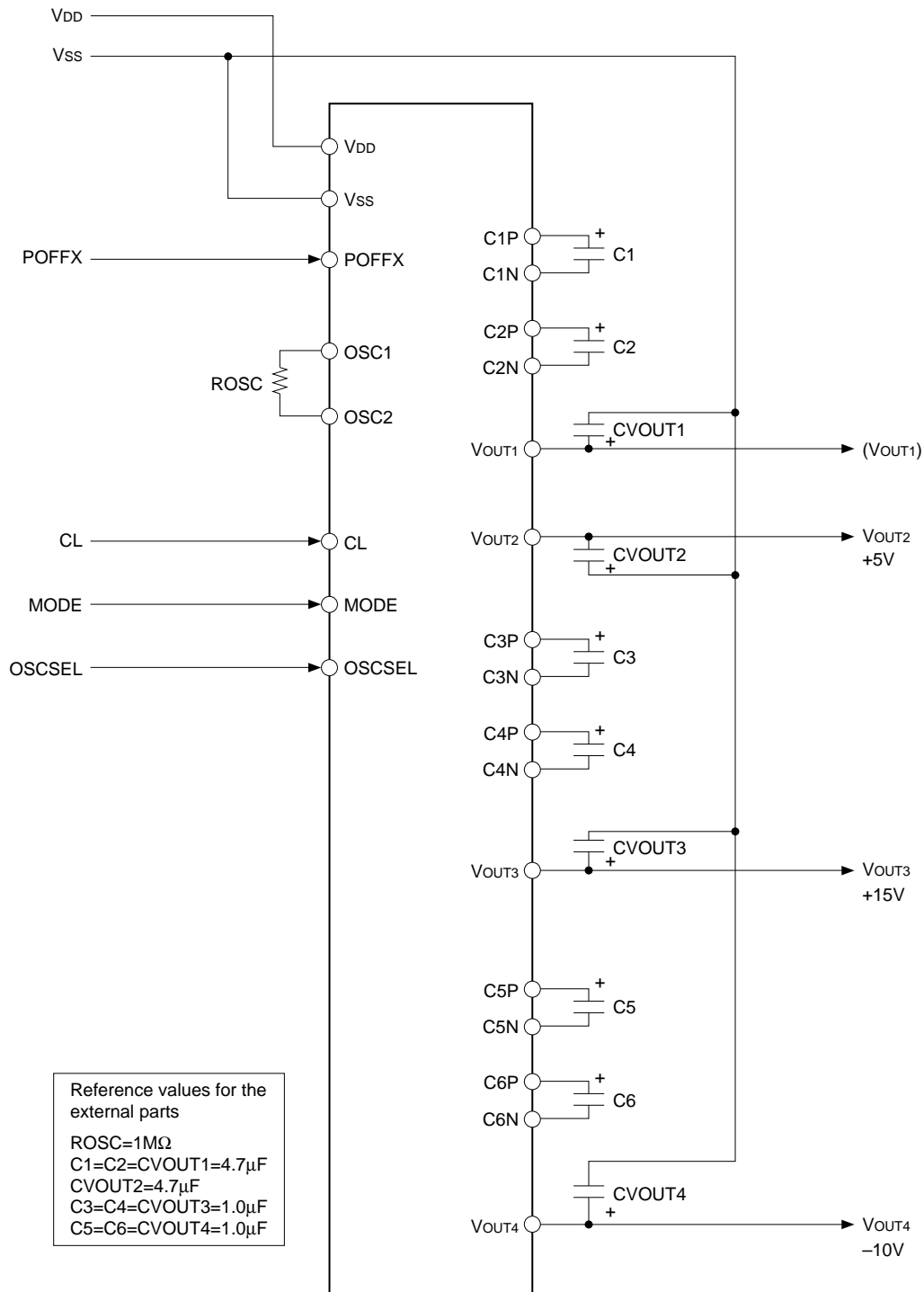


| Item                   | Symbol | Rating |      |      | Unit | Applicable pin | Remarks |
|------------------------|--------|--------|------|------|------|----------------|---------|
|                        |        | Min.   | Typ. | Max. |      |                |         |
| CL cycle               | tCCK   | 10     | —    | 1000 | μs   | CL             | —       |
| CL High pulse duration | tWHCK  | 2      | —    | —    | ns   |                |         |
| CL Low pulse duration  | tWLCK  | 2      | —    | —    | ns   |                |         |

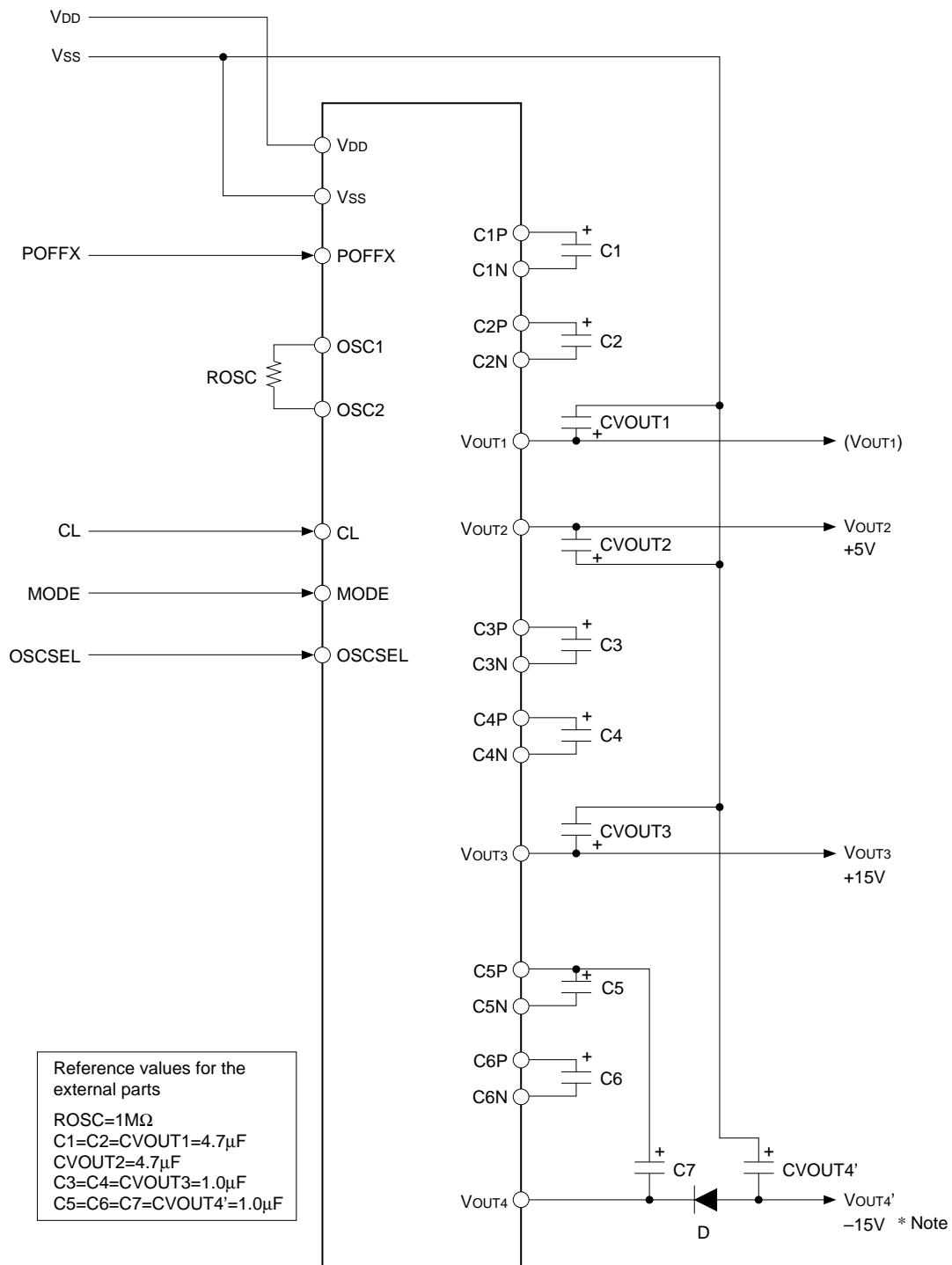
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## REFERENCE EXTERNAL CONNECTION (AN EXAMPLE)

### Standard connection (+5V, +15V, -10V Output)



## ● Extended connection (+5V, +15V, -15V Output)



\*Note : The boosting magnification of 3 times or more can be realizable by adding a diode and one capacitor at a time to the example of standard connection.

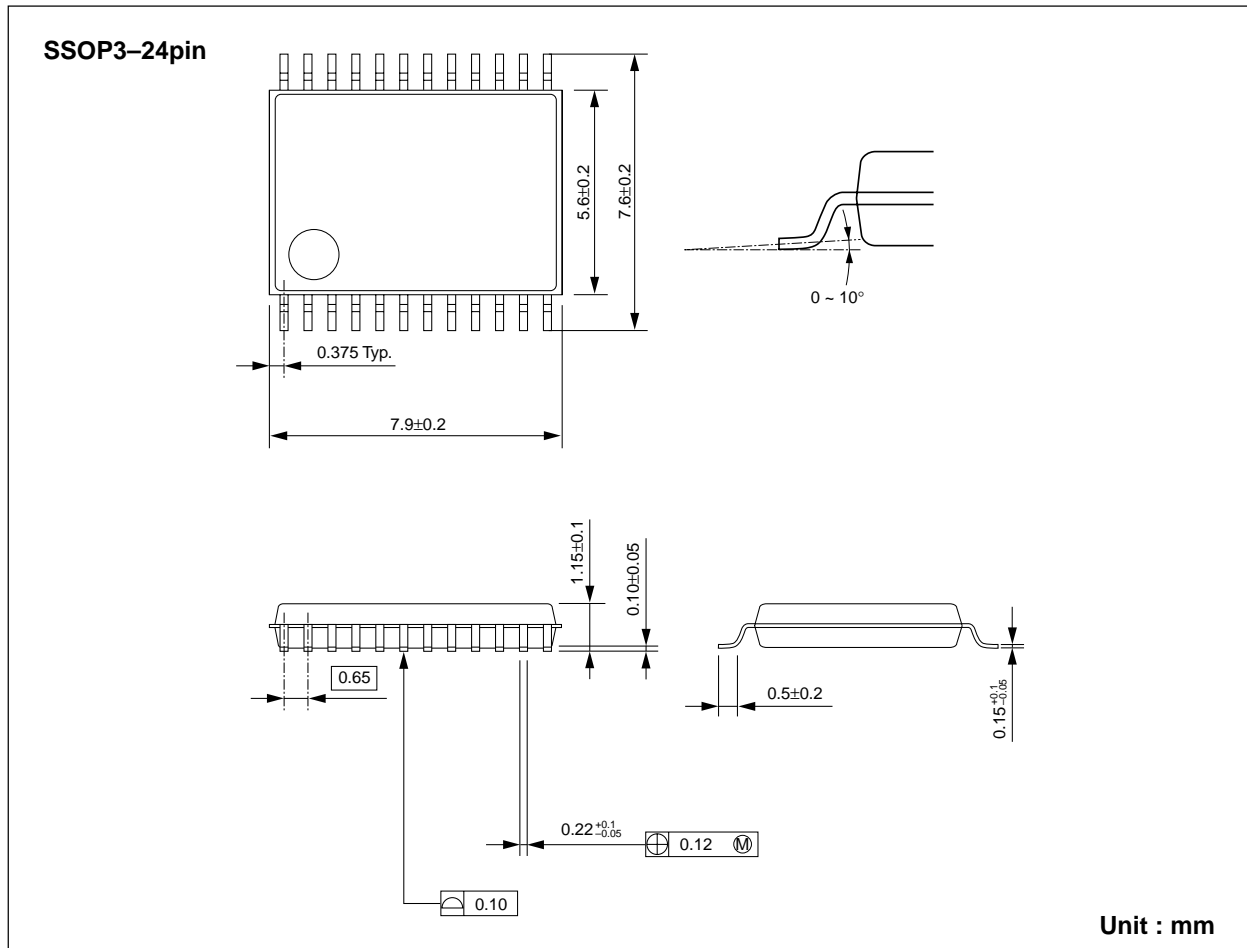
Since output impedance becomes larger under the influence of VF of a diode, the diode of low VF is recommended.

● Recommended capacitance value of external capacitor and theoretical value of voltage biased to both pins

| Circuit name                                       | Kind of capacitor      | Capacitor name | Recommended capacitance value [ $\mu$ F] | Theoretical value of voltage biased to capacitor's both pins |
|--|------------------------|----------------|--|--|
| x2 boosting circuit in the positive direction      | Flying capacitor       | C1             | 4.7                                      | $(V_{DD} - V_{SS})$  |
|  | Flying capacitor       | C2             | 4.7                                      | $(V_{DD} - V_{SS})$  |
|  | Accumulation capacitor | CVOUT1         | 4.7                                      | $(V_{OUT1} - V_{SS})$  |
| Stabilizing circuit                                | Smoothing capacitor    | CVOUT2         | 4.7                                      | $(V_{OUT2} - V_{SS})$  |
| x3 boosting circuit in the positive direction      | Flying capacitor       | C3             | 1.0                                      | $(V_{OUT2} - V_{SS})$  |
|  | Flying capacitor       | C4             | 1.0                                      | $(V_{OUT2} - V_{SS}) \times 2$                               |
|  | Accumulation capacitor | CVOUT3         | 1.0                                      | $(V_{OUT3} - V_{SS})$  |
| x3 (x4) boosting circuit in the negative direction | Flying capacitor       | C5             | 1.0                                      | $(V_{OUT2} - V_{SS})$  |
|  | Flying capacitor       | C6             | 1.0                                      | $(V_{OUT2} - V_{SS}) \times 2$                               |
|  | Flying capacitor       | C7             | 1.0                                      | $(V_{OUT2} - V_{SS}) \times 3$                               |
|  | Accumulation capacitor | CVOUT4         | 1.0                                      | $(V_{OUT4} - V_{SS})$  |
|  |                        | CVOUT4'        | 1.0                                      | $(V_{OUT4'} - V_{SS})$                                       |

<Note> "ELECTRICAL CHARACTERISTICS" are available when capacitors' capacitance values are as shown above. Since the characteristics may vary with the maximum load current, the working environment, applicable parts, etc., however, evaluate the characteristics for each application and check the capacitance values.

## ■ DIMENSIONAL OUTLINE DRAWING



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